# MSB92T1G

# **PNP Silicon General Purpose High Voltage Transistor**

This PNP Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC–59 package which is designed for low power surface mount applications.

#### Features

• This is a Pb–Free Device

### MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>(BR)CBO</sub>	-300	Vdc
Collector-Emitter Voltage	V <sub>(BR)CEO</sub>	-300	Vdc
Emitter-Base Voltage	V <sub>(BR)EBO</sub>	-5.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	150	mAdc

### THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	PD	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature Range	T <sub>stg</sub>	$-55 \sim +150$	°C

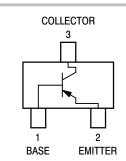
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

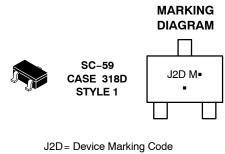
1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.



## **ON Semiconductor®**

http://onsemi.com







(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MSB92T1G	SC-59 (Pb-Free)	3000/Tape & Reel

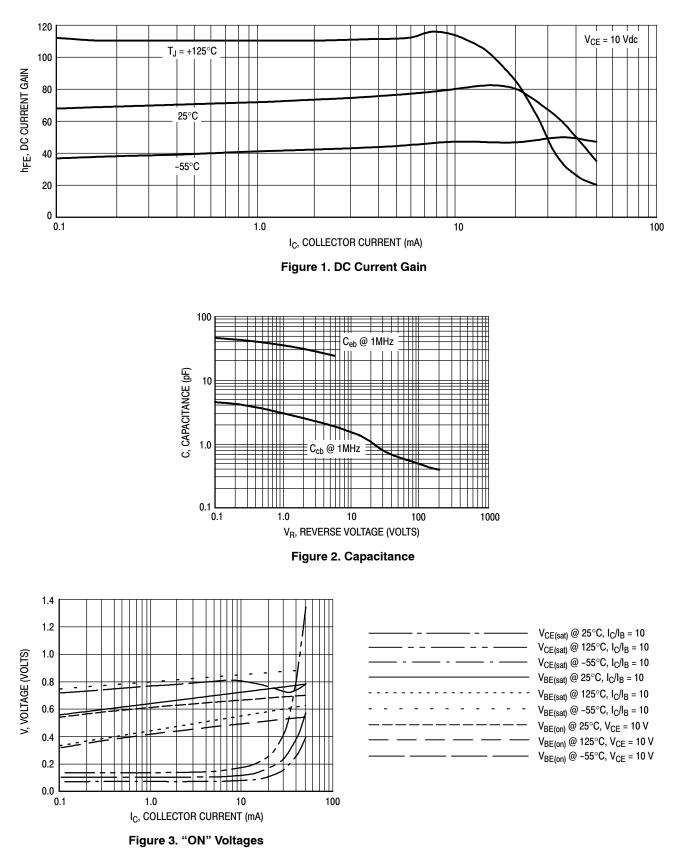
+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage ( $I_C = -1.0 \text{ mAdc}, I_B = 0$ )	V <sub>(BR)CEO</sub>	-300	-	Vdc
Collector-Base Breakdown Voltage $(I_{C} = -100 \ \mu Adc, I_{E} = 0)$	V <sub>(BR)CBO</sub>	-300	-	Vdc
Emitter-Base Breakdown Voltage ( $I_E = -100 \ \mu Adc, I_E = 0$ )	V <sub>(BR)EBO</sub>	-5.0	-	Vdc
Collector-Base Cutoff Current ( $V_{CB} = -200 \text{ Vdc}, I_E = 0$ )	I <sub>CBO</sub>	-	-0.25	μΑ
Emitter-Base Cutoff Current ( $V_{EB} = -3.0 \text{ Vdc}, I_B = 0$ )	I <sub>EBO</sub>	-	-0.1	μΑ
$ \begin{array}{l} \text{DC Current Gain (Note 2)} \\ (\text{V}_{\text{CE}} = -10 \ \text{Vdc}, \ \text{I}_{\text{C}} = -1.0 \ \text{mAdc}) \\ (\text{V}_{\text{CE}} = -10 \ \text{Vdc}, \ \text{I}_{\text{C}} = -10 \ \text{mAdc}) \\ (\text{V}_{\text{CE}} = -10 \ \text{Vdc}, \ \text{I}_{\text{C}} = -30 \ \text{mAdc}) \end{array} $	h <sub>FE1</sub> h <sub>FE2</sub> h <sub>FE3</sub>	25 40 25	- - -	-
Collector-Emitter Saturation Voltage $(I_C = -20 \text{ mAdc}, I_B = -2.0 \text{ mAdc})$	V <sub>CE(sat)</sub>	-	-0.5	Vdc
Base-Emitter Saturation Voltage ( $I_c = -20$ mAdc, $I_B = -2.0$ mAdc)	V <sub>BE(sat)</sub>	-	-0.9	Vdc
SMALL SIGNAL CHARACTERISTICS				
Current-Gain – Bandwidth Product ( $I_C = -10$ mAdc, $V_{CE} = -20$ Vdc, f = 20 MHz)	fT	50	-	MHz
Collector–Base Capacitance $(V_{CB} = -20 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>cb</sub>	-	6.0	pF

2. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, D.C.  $\leq$  2%.

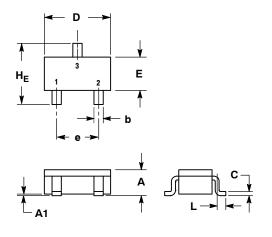
## MSB92T1G



## MSB92T1G

#### PACKAGE DIMENSIONS

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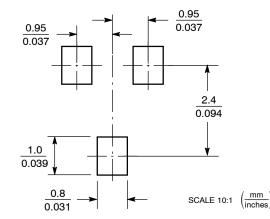


NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
q	0.35	0.43	0.50	0.014	0.017	0.020
c	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
Е	1.30	1.50	1.70	0.051	0.059	0.067
е	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.80	3.00	0.099	0.110	0.118

STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb -Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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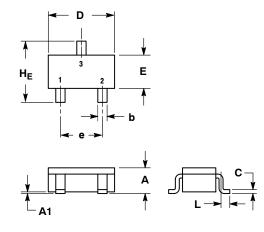
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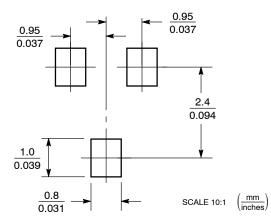




SCALE 2:1



### **SOLDERING FOOTPRINT\***



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DATE 28 JUN 2012

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e	1.70	1.90	2.10	0.067	0.075	0.083
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HE	2.50	2.80	3.00	0.099	0.110	0.118

#### GENERIC **MARKING DIAGRAM**



= Specific Device Code XXX Μ = Date Code

= Pb-Free Package\*

(\*Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE
2. EMITTER	2. N.C.	2. ANODE
3. COLLECTOR	3. CATHODE	3. CATHODE
Style 4:	Style 5:	STYLE 6:
Pin 1. Cathode	Pin 1. Cathode	PIN 1. ANODE
2. N.C.	2. Cathode	2. CATHODE
3. Anode	3. Anode	3. ANODE/CATHODE

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